

LTC3459

10V Micropower Synchronous Boost Converter

The LTC®3459 is a low current, high efficiency synchronous

boost converter intended for low power, size constrained

portable applications. The LTC3459 can be powered from

a single lithium ion battery, a 2- to 3-cell stack of alkaline

or nickel batteries, or any low impedance voltage source

between 1.5V and 5.5V. The output is programmable via

an external divider between 2.5V and 10V. Although the

part is primarily intended for boost applications, V_{OUT} will

The LTC3459 offers Burst Mode operation with a fixed

peak current, providing high conversion efficiency over

a wide range of load currents. During start-up, inductor

current is controlled preventing the inrush surge current

found in many boost converters. In shutdown the output is disconnected from the input and quiescent current is

The LTC3459 is offered in low profile 6-pin $2mm \times 2mm$

DFN, 2mm × 3mm DFN or SOT-23 (ThinSOT[™]) packages,

allowing a tiny footprint for the total solution.

trademarks are the property of their respective owners.

T, LT, LTC, LTM and Burst Mode are registered trademarks of Linear Technology Corporation. ThinSOT is a trademark of Linear Technology Corporation. All other

maintain regulation below V_{IN} (at reduced efficiency).

DESCRIPTION

reduced to <1uA.

FEATURES

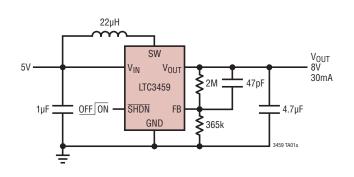
- Small Solution Size
- >85% Efficiency over Wide Load Range
- Internal Synchronous Rectifier
- V_{IN} Range: 1.5V to 5.5V
- 5V at 30mA from 3.3V Input
- 3.3V at 20mA from 2 AA Cell Input
- Programmable Output Voltages Up to 10V
- Burst Mode[®] Operation
- Inrush Current Limiting
- Output Disconnect in Shutdown
- Ultralow Quiescent (10µA) and Shutdown (<1µA) Currents
- Low Profile 2mm × 2mm DFN, 2mm × 3mm DFN or SOT-23 Package

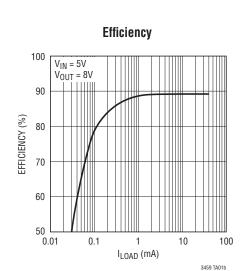
APPLICATIONS

- General Purpose Micropower Boost
- Digital Cameras
- PDAs
- LCD Bias
- Small OLED Displays
- Supercap Charging

TYPICAL APPLICATION

5V to 8V Converter





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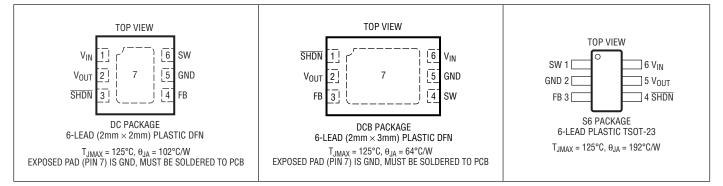
ABSOLUTE MAXIMUM RATINGS

Referred to GND (Note 1)

V _{IN} , FB Voltage	0.3V to 7V
V _{OUT} , SHDN Voltage	0.3V to 10V
SW Voltage	0.3V to 12V
Operating Temperature Range	
(Notes 2, 3)	40°C to 85°C

Storage Temperature Range	–65°C to 150°C
Reflow Temperature	260°C
Lead Temperature, S6 Package	
(Soldering, 10 sec)	300°C

PIN CONFIGURATION



ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTC3459EDC#PBF	LTC3459EDC#TRPBF	LDTG	Low Profile (2mm \times 2mm) Plastic DFN	–40°C to 85°C
LTC3459EDCB#PBF	LTC3459EDCB#TRPBF	LDMM	Low Profile (2mm \times 3mm) Plastic DFN	–40°C to 85°C
LTC3459ES6#PBF	LTC3459ES6#TRPBF	LTAHA	Low Profile SOT-23	-40°C to 85°C

Consult LTC Marketing for parts specified with wider operating temperature ranges. Consult LTC Marketing for information on non-standard lead based finish parts.

For more information on lead free part marking, go to: http://www.linear.com/leadfree/ For more information on tape and reel specifications, go to: http://www.linear.com/tapeandreel/



ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. V_{IN} = 3.3V, V_{OUT} = 5V, unless otherwise noted.

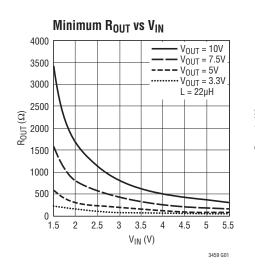
PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{IN}	I					
Input Voltage Range		•	1.5		5.5	V
V _{IN} Quiescent Current	SHDN = V _{CC}			10	20	μA
V _{IN} Shutdown Current	SHDN = GND			0.1	1	μA
V _{OUT}						<u>.</u>
Programmable Voltage Range		•	2.5		10	V
V _{OUT} Quiescent Supply Current	SHDN = V _{CC}			2	4	μA
V _{OUT} Shutdown Current	SHDN = GND			0.1	1	μA
Reference						<u></u>
Feedback Voltage	V _{IN} = 3.3V, V _{OUT} = 7.5V	•	1.19	1.22	1.25	V
FB Input Leakage Current	Measured on FB			10	50	nA
Converter Performance						
Peak Switch Current ($V_{IN} = 3.3V$)	L = 22µH	•	60	75	90	mA
t_{OFF} Timer (V _{IN} = 3.3V, V _{OUT} = 5V)	Varies by 1/(V _{OUT} - V _{IN})		225	400	550	ns
Zero Current Comparator Threshold	L = 22µH			0		mA
Main NMOS Switch		·				
On-Resistance	V _{OUT} = 5V			2.8		Ω
Leakage Current	$V_{SWITCH} = 10V, V_{OUT} = 10V$			0.01	1	μA
Main PMOS Switch		·				
On-Resistance	V _{OUT} = 5V			4.2		Ω
Leakage Current	$V_{IN} = 5V$, $V_{SWITCH} = 5V$, $V_{OUT} = 0V$			0.02	2	μA
Logic Inputs						. <u> </u>
SHDN Threshold (Rising Edge)			0.3		1	V
SHDN Hysteresis				80		mV
SHDN Input Leakage Current	SHDN = 3.3V			0	50	nA

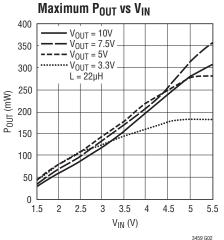
Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: The LTC3459E is guaranteed to meet performance specifications from 0°C to 85°C. Specifications over the -40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.

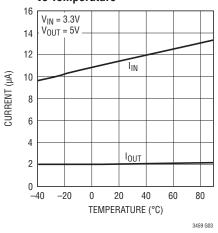
Note 3: This IC includes overtemperature protection that is intended to protect the device during momentary overload conditions. Junction temperature will exceed 125°C when overtemperature protection is active. Continuous operation above the specified maximum operating junction temperature may impair device reliability.

TYPICAL PERFORMANCE CHARACTERISTICS (T_A = 25°C, unless otherwise noted).





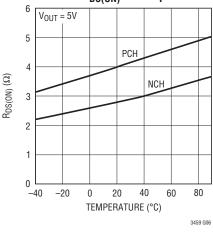
VIN and VOUT Quiescent Current vs Temperature

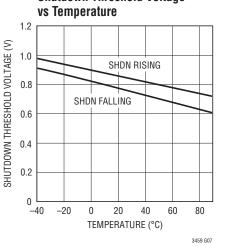


Switching Frequency vs V_{IN} at Various V_{OUTs} 3.0 $V_{OUT} = 10V$ $-V_{OUT} = 7.5V$ --V_{OUT} = 5V 2.5 $L = 22 \mu H$ FREQUENCY (MHz) 2.0 1.5 1.0 0.5 2.5 1.5 2 3 3.5 4 4.5 5 5.5

V_{OUT} Regulation vs V_{IN} and C_{OUT} 2.0 4.7µF 10µF 1.5 – 22µF •••••• 47µF 1.0 $V_{OUT} = 5V$ L = 22µH % CHANGE IN V_{OUT} 0.5 0 -0.5 -1.0 -1.5 -2.0 1.5 2 2.5 3 3.5 4 4.5 5 5.5 V_{IN} (V) 3459 G05

N-Channel and P-Channel MOSFET RDS(ON) vs Temperature

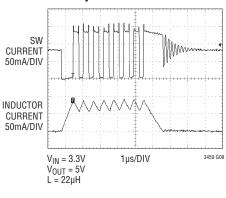




Shutdown Threshold Voltage

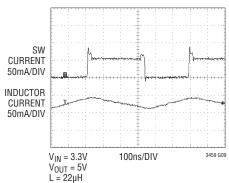
V_{IN} (V)

3459 G04



Burst Cycle

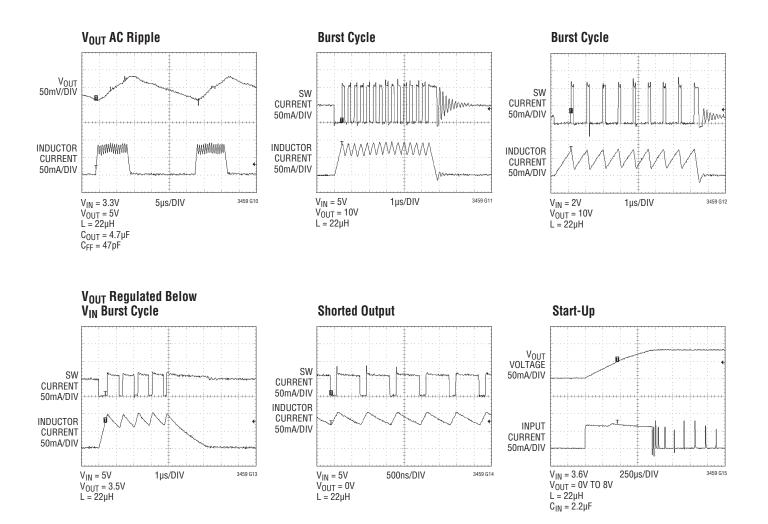
Switch Pin Waveform

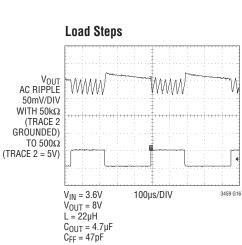




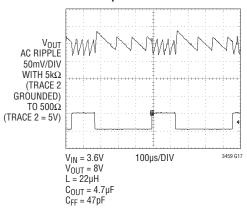


TYPICAL PERFORMANCE CHARACTERISTICS ($T_A = 25^{\circ}C$, unless otherwise noted).





Load Steps



PIN FUNCTIONS (DC/DCB/S6 Packages)

 V_{IN} (Pin 1/Pin 6/Pin 6): Input Supply Pin. Bypass V_{IN} with a low ESR, ESL ceramic capacitor of at least 1µF.

 V_{OUT} (Pin 2/Pin 2/Pin 5): Regulated Output Voltage of the Boost Regulator. Bypass V_{OUT} with a low ESR, ESL ceramic capacitor between 2.2µF and 10µF. V_{OUT} ripple increases with smaller capacitors.

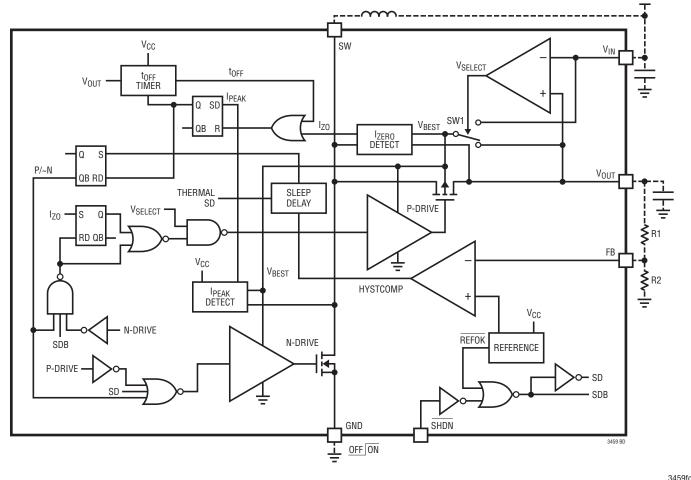
SHDN (Pin 3/Pin 1/Pin 4): Master Shutdown Input. Driving SHDN low disables all IC functions and reduces quiescent current from the battery to less than 1μ A. This pin must be pulled above 1V to enable the IC.

FB (Pin 4/Pin 3/Pin 3): Input to the Burst Mode Comparator. An external resistor divider connected between V_{OUT} , GND and this pin sets the output voltage to: **GND (Pin 5/Pin 5/Pin 2):** Signal and Power Ground. Provide a short, direct PCB path between GND and the (–) side of the filter capacitors on V_{IN} and V_{OUT} .

SW (Pin 6/Pin 4/Pin 1): Switch Pin. Connect a 15μ H to 33μ H inductor between SW and V_{IN}. Keep PCB trace lengths as short and wide as possible to reduce EMI and voltage overshoot. If the inductor current falls to zero, the internal P-channel MOSFET synchronous rectifier is turned off to prevent reverse charging of the inductor.

Exposed Pad (Pin 7/Pin 7, DC and DCB Packages Only): Ground. The Exposed Pad must be soldered to PCB.

 $V_{OUT} = 1.22(1 + R1/R2)$



BLOCK DIAGRAM



LTC3459

OPERATION

Operation

The LTC3459 synchronous boost converter utilizes a Burst Mode control technique to achieve high efficiency over a wide dynamic range. A 2.5% accurate comparator is used to monitor the output voltage (V_{OUT}), if V_{OUT} is above the comparator threshold, no switching occurs and only quiescent current (10µA) is drawn from the power source. When V_{OUT} drops below the comparator threshold, switching commences and the output capacitor is charged. During the on time of the switching period, inductor current is ramped through an internal N-channel MOSFET to GND until a peak current (75mA) is detected. A P-channel MOSFET connects the inductor to V_{OUT} during the off time delivering energy to the load. The off time is controlled by an internal timer which is proportional to $1/(V_{OUT} - V_{IN})$. Anticross conduction circuitry ensures the N- and P-channel switches are never on simultaneously.

Only three power components and two feedback resistors are required to complete the design of the boost converter, an external Schottky diode is not required. The high operating frequency allows the use of low value, low profile inductors and tiny external ceramic capacitors. The boost converter disconnects V_{OUT} from V_{IN} during shutdown to avoid loading the input power source.

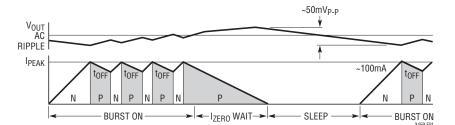
Peak Current Overshoot

The LTC3459's peak current comparator has a delay of approximately 100ns from the time inductor current reaches current limit until the internal N-channel MOSFET turns off. This delay causes the peak current to overshoot based on the inductor value and V_{IN} , as follows (Figure 2 is based on a 65mA initial I_{LIMIT}).

$$I_{\text{PEAK}} = I_{\text{LIMIT}} + (100 \text{ns}) \frac{V_{\text{IN}}}{L}$$

t_{OFF} Timer

The LTC3459's t_{OFF} timer is designed to keep the inductor current continuous during a Burst Mode switching packet, thereby increasing current capability at the output. A larger inductor value will have lower peak-to-peak current ripple, increasing the available current to the load. This improvement is offset somewhat by the reduced I_{PEAK} overshoot. The t_{OFF} timer is designed to maintain a relatively constant peak-to-peak current in the inductor despite V_{IN} changes.



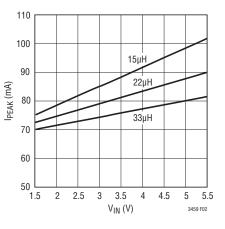
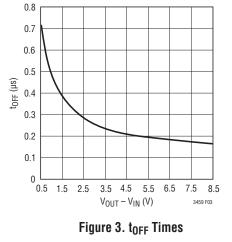


Figure 2. Typical I_{PEAK} Values





OPERATION

This is accomplished by varying the t_{OFF} period by approximately $1/(V_{OUT} - V_{IN})$. Due to propagation delays and a 0.6µA bias current in the timer, the t_{OFF} time can be more accurately predicted as follows:

$$t_{OFF} \approx 100 \text{ns} + \frac{0.8 \text{pF} \bullet 1.25 \text{V}}{0.6 \mu \text{A} + \frac{\text{V}_{OUT} - \text{V}_{\text{IN}}}{500 \text{k}}}$$

If V_{OUT} is less than $V_{\text{IN}},$ the t_{OFF} delay is fixed at approximately 750ns.

APPLICATIONS INFORMATION

Inductor Selection

An inductor with a minimum value of 15μ H is recommended for use with the LTC3459. Values larger than 15μ H will result in lower ripple current and switching frequency. High frequency ferrite core materials are strongly recommended. Some inductors meeting these requirements are listed in Table 1.

VENDOR/PART	L (µH)	DCR (Ω)/ I _{MAX} (mA)	DIMENSIONS (mm)	CONTACT INFORMATION	
Chip Inductors					
Murata LQH31C LQH32C-Low Profile	22 22	3/160 0.7/250	3.2×1.6×1.8 3.2×2.5×1.6	www.murata.com	
Taiyo Yuden LB2016	15 22 33	0.7/130 1/105 1.7/85	2.0×1.6×1.6	www.t-yuden.com (408) 573-4150	
Toko LLB2520	15 22 33	1.7/180 2.5/160 3.8/130	2.5×2.0×1.6	www.tokoam.com (847) 297-0070	
Coilcraft D03314 D01606T	15 22 15	0.86/650 1.2/500 0.4/700	$3.3 \times 3.3 \times 1.4$ $6.5 \times 5.3 \times 2.0$	www.coilcraft.com (847) 639-6400	
	22 33	0.5/500 0.74/450			
Sumida CMD4D06	15 22	0.5/400 0.8/300	6.6×5.8×0.8	www.sumida.com (847) 956-0666	
CDRJ2D1BLD	33 15 22 33	1.3/240 0.175/350 0.255/300 0.37/240	3.2×3.2×2.0		

Table 1. Example Inductors

Capacitor Selection

The boost converter requires two capacitors. The input capacitor should be an X5R type of at least 1.0μ F. The V_{OUT} capacitor should also be an X5R type between 2.2μ F and 10μ F. A larger capacitor should be used if lower peak-topeak output ripple and better line regulation is desired.

Table 2. Capacitor Vendor Information

SUPPLIER	PHONE	WEBSITE	
AVX	(803) 448-9411	www.avxcorp.com	
Murata	(714) 852-2001	www.murata.com	
Taiyo Yuden	(408) 573-4150	www.t-yuden.com	
TDK	(847) 803-6100	www.component.tdk.com	

PCB Layout Guidelines

The high speed operation of the LTC3459 demands careful attention to board layout. You will not get advertised performance with a careless layout. Figure 4 shows the recommended component placement for the TSOT version of the part. A large ground pin copper area will help to lower the chip temperature.

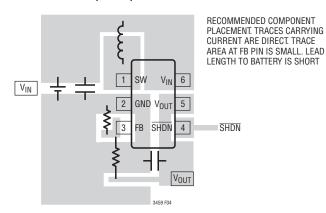


Figure 4. Recommended Component Placement for a Single-Layer Board



TYPICAL APPLICATIONS

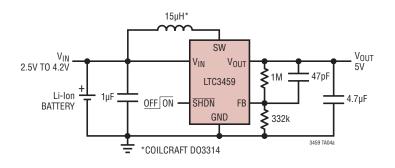
Very low operating quiescent current and synchronous operation allow for greater than 85% conversion efficiency in many applications. Lower output voltages will result in lower efficiencies since the N- and P-channel $R_{DS(ON)}$ s will increase. The switching frequency and output power capability of the LTC3459 are also dependent on input and output voltages.

Charging a SuperCap®

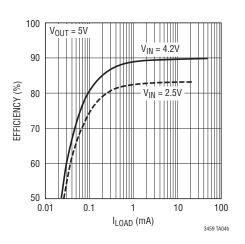
SuperCaps have become a popular alternative to NiCd batteries as back-up power sources in portable equipment. Capacitance values of one farad and higher are achievable in small package sizes with leakage currents in the low microamps. SuperCaps are typically charged at low currents for several minutes until they reach the required back-up voltage.

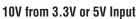
The LTC3459 is designed to control peak inductor current when V_{IN} is greater than or less than V_{OUT}. This allows current to be controlled during start-up in a boost application, for example, or V_{OUT} to be regulated below V_{IN} when powered from a fresh battery. Peak current control makes the LTC3459 an ideal candidate for charging a back-up source such as a SuperCap. Figure 5 shows an application where the LTC3459 is used to charge a two-farad, 5V SuperCap from a 3.3V input. A NiCd battery could be charged by the LTC3459 as well, but that application may require additional circuitry for proper charge termination.

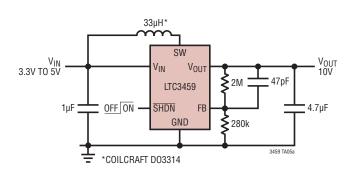
When V_{OUT} is less than ~3.5V, the body of the internal synchronous P-channel MOSFET rectifier is connected to V_{IN} , and the SW pin rises a diode above V_{IN} when current is delivered to the load. While efficiency is compromised in this mode of operation, current to the SuperCap is

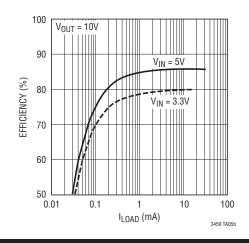








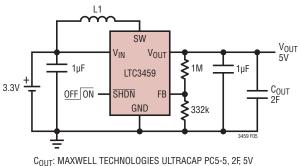






TYPICAL APPLICATIONS

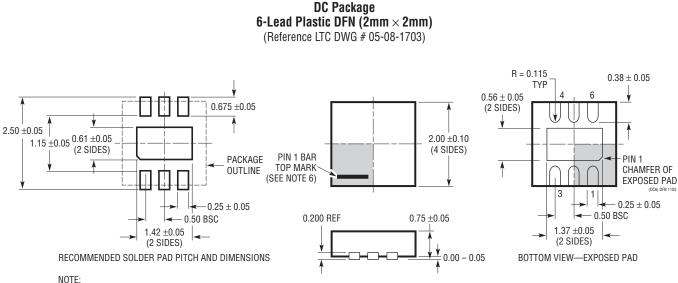
controlled, preventing any damaging effects of inrush current. Proper heat sinking of the package is required in this application as the die may dissipate 100mW to 200mW during initial charging. When V_{OUT} is greater than ~3.5V, normal boost mode operation and efficiency begin, with the P-channel MOSFET acting as a synchronous switch. Average input current is a constant 50mA during charging, where the current delivered to the SuperCap varies somewhat with duty cycle. Once the SuperCap is charged to 5V, the LTC3459 begins to regulate and the input current is reduced to the amount required to support the load and/or self discharge of the SuperCap.



 C_{OUT} : MAXWELL TECHNOLOGIES ULTRACAP PC5-5, 2F, 5 L1: 33µH, 1.7 Ω TAIYO YUDEN LB2016

Figure 5. Charging a SuperCap from a 3.3V Source

PACKAGE DESCRIPTION



1. DRAWING TO BE MADE A JEDEC PACKAGE OUTLINE M0-229 VARIATION OF (WCCD-2)

2. DRAWING NOT TO SCALE

3. ALL DIMENSIONS ARE IN MILLIMETERS

4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE

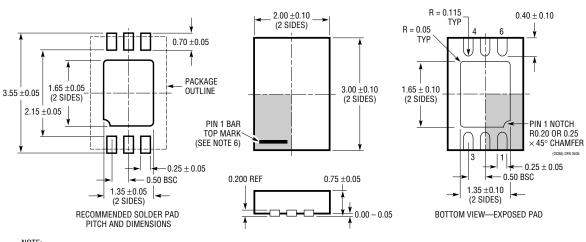
MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE 5. EXPOSED PAD SHALL BE SOLDER PLATED

6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE

TOP AND BOTTOM OF PACKAGE



PACKAGE DESCRIPTION



DCB Package 6-Lead Plastic DFN ($2mm \times 3mm$) (Reference LTC DWG # 05-08-1715)

NOTE:

1. DRAWING TO BE MADE A JEDEC PACKAGE OUTLINE M0-229 VARIATION OF (TBD) 2. DRAWING NOT TO SCALE 3. ALL DIMENSIONS ARE IN MILLIMETERS

4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE

(Reference LTC DWG # 05-08-1636) 2.90 BSC 0.62 0.95 (NOTE 4) MAX REF 1.22 REF 1.50 - 1.75 2.80 BSC 3.85 MAX 2.62 REF 1.4 MIN (NOTE 4) PIN ONE ID RECOMMENDED SOLDER PAD LAYOUT 0.30 - 0.45 0.95 BSC PER IPC CALCULATOR 6 PLCS (NOTE 3) 0.80 - 0.90 0.20 BSC 0.01 - 0.10 1.00 MAX DATUM 'A' ۲ 0.30 - 0.50 REF 1.90 BSC 0.09 - 0.20 (NOTE 3) S6 TS0T-23 0302 BEV B NOTE 1. DIMENSIONS ARE IN MILLIMETERS 4. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR 2. DRAWING NOT TO SCALE 5. MOLD FLASH SHALL NOT EXCEED 0.254mm 3. DIMENSIONS ARE INCLUSIVE OF PLATING 6. JEDEC PACKAGE REFERENCE IS MO-193

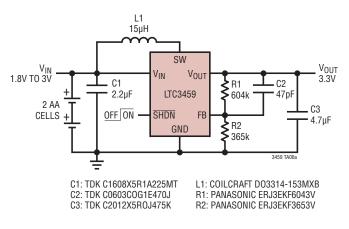


5. EXPOSED PAD SHALL BE SOLDER PLATED

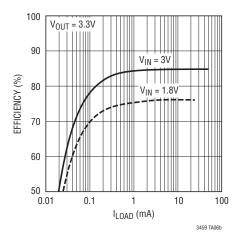
6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE

Information furnished by Linear Technology Corporation is believed to be accurate and reliable. However, no responsibility is assumed for its use. Linear Technology Corporation makes no representation that the interconnection of its circuits as described herein will not infringe on existing patent rights.

TYPICAL APPLICATION



3.3V from a 2 AA Alkaline Input



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1310	1.5A I _{SW} , 4.5MHz, High Efficiency Step-Up DC/DC Converter	V_{IN} : 2.75V to 18V, $V_{OUT(MAX)}$ = 35V, I_Q = 12mA, I_{SD} < 1 μ A, MS10E
LT1613	550mA I _{SW} , 1.4MHz, High Efficiency Step-Up DC/DC Converter	V_{IN} : 0.9V to 10V, $V_{OUT(MAX)}$ = 34V, I_Q = 3mA, I_{SD} < 1µA, ThinSOT
LT1615/ LT1615-1	300mA/80mA I _{SW} , Constant Off-Time, High Efficiency Step-Up DC/DC Converter	V_{IN} : 1.2V to 15V, $V_{OUT(MAX)}$ = 34V, I_Q = 20µA, I_{SD} < 1µA, ThinSOT
LT1618	1.5A I _{SW} , 1.4MHz, High Efficiency Step-Up DC/DC Converter	V_{IN} : 1.6V to 18V, $V_{\text{OUT}(\text{MAX})}$ = 35V, I_{Q} = 1.8mA, I_{SD} < 1µA, MS10
LT1944 (Dual)	Dual Output 350mA I _{SW} , Constant Off-Time, High Efficiency Step-Up DC/DC Converter	$V_{IN}\!\!:$ 1.2V to 15V, $V_{OUT(MAX)}$ = 34V, I_Q = 20µA, I_{SD} < 1µA, MS10
LT1945 (Dual)	Dual Output Pos/Neg 350mA I _{SW} , Constant Off-Time, High Efficiency Step-Up DC/DC Converter	$V_{IN}\!\!:$ 1.2V to 15V, $V_{OUT(MAX)}$ = ±34V, I_Q = 20µA, I_{SD} < 1µA, MS10
LT1946/ LT1946A	1.5A I _{SW} , 1.2MHz/2.7MHz, High Efficiency Step-Up DC/DC Converter	$V_{IN}\!\!:$ 2.45V to 16V, $V_{OUT(MAX)}$ = 34V, I_Q = 3.2mA, I_{SD} < 1µA, MS8
LT1949/ LT1949-1	550mA I _{SW} , 600kHz/1.1MHz, High Efficiency Step-Up DC/DC Converter	$V_{IN}\!\!:$ 1.5V to 12V, $V_{OUT(MAX)}$ = 28V, I_Q = 4.5mA, I_{SD} < 25 $\mu\text{A},$ S0-8, MS8
LT1961	1.5A I _{SW} , 1.25MHz, High Efficiency Step-Up DC/DC Converter	V_{IN} : 3V to 25V, $V_{\text{OUT}(\text{MAX})}$ = 35V, I_{Q} = 0.9mA, I_{SD} < 6µA, MS8E
LTC3400/ LTC3400B	600mA I _{SW} , 1.2MHz, Synchronous Step-Up DC/DC Converter	V_{IN} : 0.5V to 5V, $V_{\text{OUT}(\text{MAX})}$ = 5V, I_{Q} = 19µA/300µA, I_{SD} < 1µA, ThinSOT
LTC3401	1A I _{SW} , 3MHz, Synchronous Step-Up DC/DC Converter	V_{IN} : 0.5V to 5V, $V_{\text{OUT}(\text{MAX})}$ = 6V, I_{Q} = 38µA, I_{SD} < 1µA, MS10
LTC3402	2A I _{SW} , 3MHz, Synchronous Step-Up DC/DC Converter	V_{IN} : 0.5V to 5V, $V_{OUT(MAX)}$ = 6V, I_Q = 38µA, I_{SD} < 1µA, MS10
LTC3425	5A I _{SW} , 8MHz, 4-Phase Synchronous Step-Up DC/DC Converter, QFN32	V_{IN} : 0.5V to 4.5V, $V_{OUT(MAX)}$ = 5.25V, I_Q = 12µA, I_{SD} < 1µA,
LTC3429	600mA, 500kHz, Synchronous Step-Up DC/DC Converter with Output Disconnect and Soft-Start	V_{IN} : 0.5V to 5V, $V_{\text{OUT}(\text{MAX})}$ = 5V, I_{Q} = 20µA/300µA, I_{SD} < 1µA, ThinSOT
LT3460	320mA I _{SW} , 1.3MHz, High Efficiency Step-Up DC/DC Converter	V_{IN} : 0.5V to 5V, $V_{OUT(MAX)}$ = 5V, I_Q = 20µA/300µA, I_{SD} < 1µA, ThinSOT
LT3464	85mA I _{SW} , Constant Off-Time, High Efficiency Step-Up DC/DC Converter with Integrated Schottky/Output Disconnect	V_{IN} : 2.3V to 10V, $V_{\text{OUT}(\text{MAX})}$ = 34V, I_{Q} = 25µA, I_{SD} < 1µA, ThinSOT



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